



Future Normal in Semiconductor

2025-02-13(목), 09:00-10:45

좌장: 추후업데이트 예정

M. RF and Wireless Design 분과

[TM1-H] RF Transceiver

<p>초청 TL1-M-1 09:00-09:30</p>	<p>Low-Power and Low-Cost RFIC Supporting Legacy Cellular and 5G FR1 Jongsoo Lee Samsung Electronics Co., Ltd.</p>
<p>TL1-M-2 09:30-09:45</p>	<p>Low-Noise IIP2 Calibration-free Receiver Front-End with Dual RF and BB N-path Filters for 5G New Radio Cellular Applications Sukju Yun, Kuduck Kwon Department of Electronics Engineering, Kangwon National University</p>
<p>TL1-M-3 09:45-10:00</p>	<p>An 8x8 Optoelectronic Readout Array Using T2V Converter in 180-nm CMOS for Short-Range LiDAR Sensors Sunkyoung Lee^{1,2}, Somi Park^{1,2}, Bobin Seo^{1,2}, and Sung Min Park^{1,2} ¹Division of Electronic & Semiconductor Engineering, Ewha Womans University, ²Graduate Program in Smart Factory, Ewha Womans University</p>
<p>초청 TL1-M-4 10:00-10:30</p>	<p>Gbps Level High-Speed Communication Ultra-Wideband (UWB) Transceiver Research for Brain Computing Interfaces (BCIs) Geunhaeng Lee Andong National University</p>
<p>TL1-M-5 10:30-10:45</p>	<p>55 W 3.4-3.8 GHz 2-Stage Doherty Power Amplifier for 5G NR 배순철¹, 송재성¹, 이윤정¹, 배경동^{1,2}, 양영구^{1,2} ¹성균관대학교 전자전기컴퓨터공학과, ²Para-PA Inc.</p>